

MTX2-133-D+

500 1500 to 13000 MHz

THE BIG DEAL

- Wideband, 1500 to 13000 MHz
- · Low insertion loss, 1.9 dB typ. (above theoretical) at 7000 MHz
- Excellent Common Mode Rejection, 34 dB typ.

EL-BAL-2_1

+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

SEE ORDERING INFORMATION ON THE LAST PAGE

APPLICATIONS

- · Cellular Infrastructure
- Instrumentation
- RADAR
- Satcom
- Electronic Warfare
- Mixers & Modulators

PRODUCT OVERVIEW

Mini-Circuits MTX2-133-D+ is a wideband MMIC balun transformer die with an impedance ratio of 1:2 applicable for a wide range of applications from 1500 to 13000 MHz. Fabricated using GaAs HBT process technology, this model provides outstanding repeatability with low insertion loss, low amplitude unbalance, low phase unbalance, and excellent common mode rejection.

KEY FEATURES

Feature	Advantages
Wideband, 1500 to 13000 MHz	MTX2-133-D+ supports a broad variety of applications including instrumentation, WLAN, WiMAX, WiBRO, ISM, radar and more.
Low insertion loss - 1.9 dB typ. (above theoretical) at 7000 MHz	Enables excellent signal power transmission from input to output.
Low unbalance • 0.3 dB typ. amplitude unbalance • 1.2° typ. phase unbalance	Low unbalance can improve a system's electromagnetic compatibility by rejecting unwanted common-mode noise.
Excellent Common Mode Rejection - 34 dB typ.	Enables rejection of undesired signals
Unpackaged Die	Enables the user to integrate the balun directly into hybrids.

REV. OR ECO-010992 MTX2-133-D+ MCLNY 211207





MTX2-133-D+

ELECTRICAL SPECIFICATIONS¹ AT 25°C, 50Ω, UNLESS OTHERWISE NOTED.

Parameter	Frequency (MHz)	Min.	Тур.	Max.	Unit
Impedance Ratio (secondary / primary)			2		
Frequency Range		1500		13000	MHz
	1500-3000		2.3		
Insertion Loss (Above 3 dB Theoretical)	3000-10000		1.9		dB
	10000-13000		2.9		
	1500-3000		0.6		
Amplitude Unbalance	3000-10000		0.2		dB
	10000-13000		0.4		
	1500-3000		3.0		
Phase Unbalance ²	3000-10000		0.8		Degree
	10000-13000		1.2		
	1500-3000		28		
Common Mode Rejection Ratio	3000-10000		36		dB
	10000-13000		33		
	1500-3000		11		
Input Return Loss	3000-10000		14		dB
	10000-13000		17		

^{1.} Measured on X-Microwave Die Characterization test board.

MAXIMUM RATINGS³

Parameter	Ratings
Operating Temperature	-40°C to 85°C
Input RF Power	33 dBm at 25°C

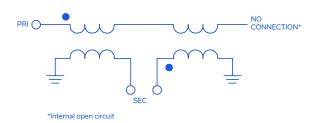
^{3.} Permanent damage may occur if any of these limits are exceeded.

^{2.} Relative to 180°



MTX2-133-D+

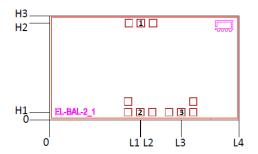
SIMPLIFIED SCHEMATIC



PAD DESCRIPTION

Pad Number	Description
1	Primary Dot
2	Secondary
3	Secondary Dot

BONDING PAD POSITION

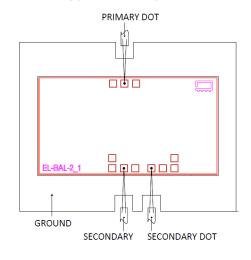


DIE DIMENSIONS IN µm

L1	L2	L3	L4	H1	H2	Н3
1131	1139	1643	2370	96	1207	1300

Thickness	Die Size	Pad Size 1,2 & 3	
100	2370 x 1300	89 x 89	

ASSEMBLY DIAGRAM



ASSEMBLY PROCEDURE

1. Storage

Dice should be stored in a dry nitrogen purged desiccators or equivalent.



ESD

MMIC GaAs HBT RF Transformer dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static worksta tion. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.

3. Die Attach

The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are Ablestik 84-1 LMISR4 or equivalents. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.

4. Wire Bonding

Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.



MTX2-133-D+

ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD.

Performance Data	Data Table	Data Table			
	Swept Graphs	Swept Graphs			
	S-Parameter (S3P Files) Data Set with and with	S-Parameter (S3P Files) Data Set with and without port extension(.zip file)			
Case Style	Die	Die			
Die Ordering and packaging information	Quantity, Package Small, Gel - Pak: 5,10,50,100 KGD* Medium†, Partial wafer: KGD*<672 †Available upon request contact sales represe Refer to AN-60-067	Model No. MTX2-133-DG+ MTX2-133-DP+ ntative			
Environmental Ratings	ENV80				

^{*}Known Good Dice ("KGD") means that the dice are taken from PCM good wafer and visually inspected. While this is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

NOTES

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